

# MPS-081017N-02

800 to 960 MHz Amplifier
Ultra Low Noise / High Linearity
Preliminary Data Sheet

#### **Features:**



13.5 dB Gain

+21 dBm P1dB

Single Positive Bias

Leadless Surface Mount Package (02)



The MPS-081017N-02 is a low noise, high dynamic range amplifier suitable for base station receiver and transmitter driver applications. The high output IP3 makes it ideal as a driver stage for low distortion applications. It is ideally suited for complex modulation schemes such as 2G, 2.5G, 3G, GSM, TDMA, EDGE, UMTS, WCDMA, CDMA2000, and TD-SCDMA applications.

### **Electrical Specifications** @ 25°C, Vdd = 6.0 to 7.0 $V^*$ , Zo = 50 ohms

SYMBOL	PARAMETERS	Min	Typical	Max	Unit
Freq.	Frequency Range	800		960	MHz
SSG	Small Signal Gain	12.0	13.5		dB
P1 dB	Pout at 1 dB Comp Point		+21.0		dBm
IP3	Third-Order Intercept		36.0		dBm
NF	Noise Figure		1.0	1.3	dB
VSWR	VSWR (Input/Output)		2.0:1		
GOF	Gain Var. over 40 MHz		± 0.2	± 0.5	dB
GOT	Gain Var. over Temp		-0.015		dB/℃
ldd	DC Current		180	250	mA

<sup>\*</sup>Vdd = 6.0 - 7.0 volts for best operation.

### **Absolute Maximum Ratings**

Maximum Bias Voltage	7.5 V		
Maximum Continuous RF Input Power	+25 dBm		
Maximum Peak Input Power	+27 dBm		
Maximum Case Operating Temperature	+85 ℃		
Maximum Storage Temperature	- 65 to + 150 ℃		

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#### **Outline Diagram**



